

Description

DO-15 P Series solid state protection thyristor protect telecommunications equipment such as modems, line cards, fax machines, and other CPE.

P Series devices are used to enable equipment to meet various regulatory requirements including GR 1089, ITU K.20, K.21 and K.45, IEC 60950, UL 60950, and TIA-968 (formerly known as FCC Part 68).



Compared to surge suppression using other technologies, P Series devices offer absolute surge protection regardless of the surge current available and the rate of applied voltage (dv/dt). P Series devices:

- Cannot be damaged by voltage
- Eliminate hysteresis and heat dissipation typically found with clamping devices
- Eliminate voltage overshoot caused by fast-rising transients
- Are non-degenerative
- Will not fatigu
- Have low capacitance, making them ideal for high-speed transmission equipment

Electrical Parameters

Parameter	Definition
C_0	Off-state Capacitance — typical capacitance measured in off state
di/dt	Rate of Rise of Current — maximum rated value of the acceptable rate of rise in current over time
I_S	Switching Current — maximum current required to switch to on state
I_{DRM}	Leakage Current — maximum peak off-state current measured at V_{DRM}
I_H	Holding Current — minimum current required to maintain on state
I_{PP}	Peak Pulse Current — maximum rated peak impulse current
I_T	On-state Current — maximum rated continuous on-state current
I_{TSM}	Peak One-cycle Surge Current — maximum rated one-cycle AC current
V_S	Switching Voltage — maximum voltage prior to switching to on state
V_{DRM}	Peak Off-state Voltage — maximum voltage that can be applied while maintaining off state
V_F	On-state Forward Voltage — maximum forward voltage measured at rated on-state current
V_T	On-state Voltage — maximum voltage measured at rated on-state current



Over-voltage Protection Thyristor
SP0900LB
ROHS
Electrical Characteristics

Part Number*	V _{DRM} Volts	V _S Volts	V _T Volts	I _{DRM} μ Amps	I _S mAmps	I _T Amps	I _H mAmps	C _O pF
SP0900LB	75	98	4	5	800	2.2	150	40

* For surge ratings, see table below.


Notes:

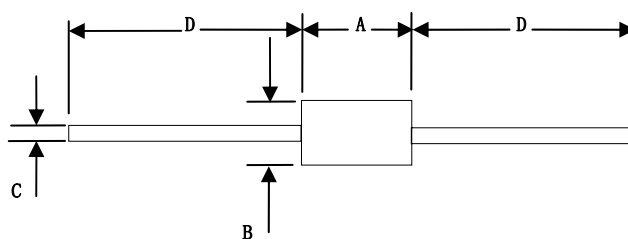
- All measurements are made at an ambient temperature of 25°C. I_P applies to -40°C through +85°C temperature range.
- Off-state capacitance (C_O) is measured at 1 MHz with a 2 V bias and is typical value.

Surge Ratings

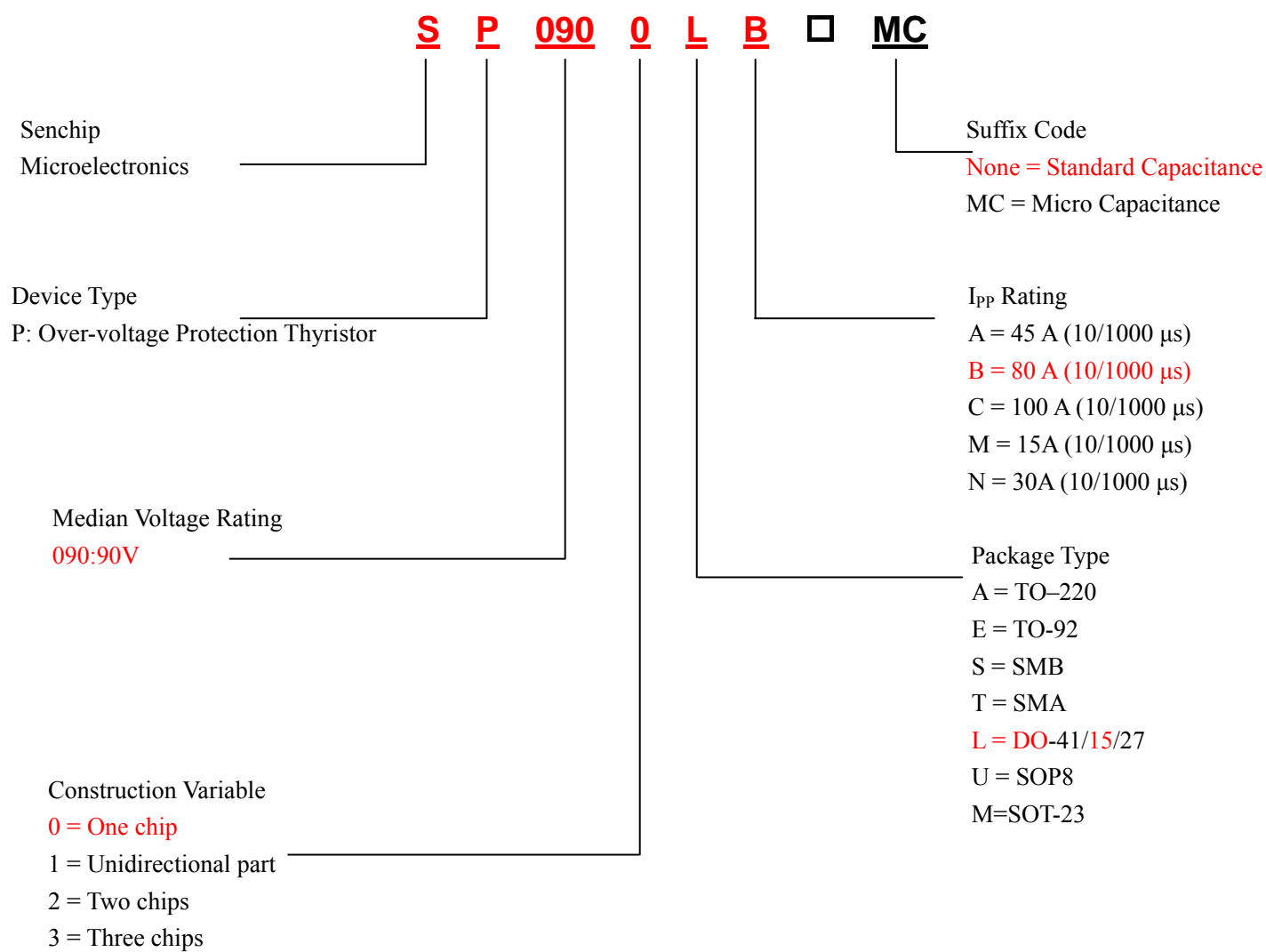
Series	I _{PP} 2/10 μ s Amps	I _{PP} 8/20 μ s Amps	I _{PP} 10/160 μ s Amps	I _{PP} 10/560 μ s Amps	I _{PP} 10/1000 μ s Amps	I _{TSM} 60 Hz Amps	di/dt Amps/μ s
B	250	250	150	100	80	30	500

Thermal Considerations

Package	D0-15	Symbol	Parameter	Value	Unit
		T _J	Operating Junction Temperature	-40 to +150	°C
		T _S	Storage Temperature Range	-40 to +150	°C
		R _{θJA}	Junction to Ambient on printed circuit	90	°C/W

Dimensions


Dimension	Inches		Millimeters		NOTE
	MIN	MAX	MIN	MAX	
A	0.230	0.300	5.80	7.60	
B	0.104	0.140	2.60	3.60	ϕ
C	0.026	0.034	0.70	0.90	ϕ
D	1.000		25.40		

Description of Part Number


Description of Marking

Device Type

S: Senchip Over-voltage
Protection Thyristor

09: 90V (VBR Median
Voltage Rating)

08: 2008

The last two numbers of
year.

L: DO-41/15/27

I_{PP} Rating

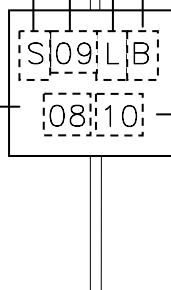
A = 45 A (10/1000 μ s)

B = 80 A (10/1000 μ s)


C = 100 A (10/1000 μ s)

10: October

The two numbers of
month.

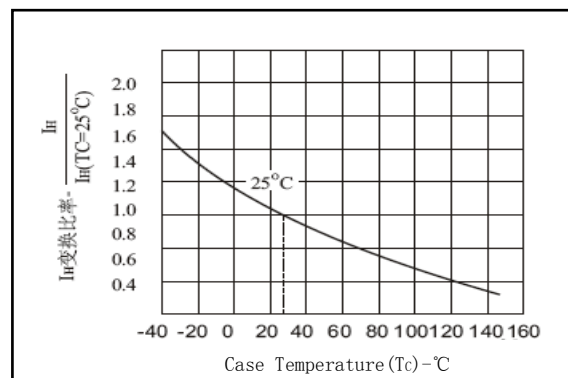


Summary of Packing Options

Package Type	Description	Packing Quantity	Industry Standard
D0-15 	Embossed Carrier Reel Pack	2000 PCS	EIA RS-481

Thermal Derating Curves


Normalized VS Change versus Junction Temperature



Normalized DC Holding Current versus Case Temperature


E313687